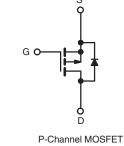
# Power MOSFET

PRODUCT SUMMAI	RY .		
V <sub>DS</sub> (V)	- 100		
R <sub>DS(on)</sub> (Ω)	V <sub>GS</sub> = - 10 V	0.20	
Q <sub>g</sub> (Max.) (nC)	6	1	
Q <sub>gs</sub> (nC)	1	4	
Q <sub>gd</sub> (nC)	2	9	
Configuration	Single		





### **FEATURES**

- Dynamic dV/dt Rating
- Repetitive Avalanche Rated
- P-Channel
- Isolated Central Mounting Hole
- 175 °C Operating Temperature
- · Fast Switching
- Ease of Paralleling
- Compliant to RoHS Directive 2002/95/EC

### DESCRIPTION

Third generation Power MOSFETs from Vishay provide the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost-effectiveness.

The TO-247AC package is preferred for commercial-industrial applications where higher power levels preclude the use of TO-220AB devices. The TO-247AC is similar but superior to the earlier TO-218 package because of its isolated mouting hole. It also provides greater creepage distance between pins to meet the requirements of most safety specifications.

ORDERING INFORMATION	
Package	TO-247AC
Lead (Pb)-free	IRFP9140PbF
	SiHFP9140-E3
SnPb	IRFP9140
	SiHFP9140

ABSOLUTE MAXIMUM RATINGS (T <sub>C</sub>	= 25 °C, unless other	wise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V <sub>DS</sub>	- 100	V
Gate-Source Voltage	V <sub>GS</sub>	± 20	v	
Continuous Drain Current $V_{GS}$ at - 10 V $T_C = 25 \ ^{\circ}C$ $T_C = 100 \ ^{\circ}C$		°C	- 21	
Continuous Drain Current	$V_{GS} a = 10 V T_{C} = 100$	°C I <sub>D</sub>	- 15	A
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	- 84	
Linear Derating Factor			1.2	W/°C
Single Pulse Avalanche Energy <sup>b</sup>		E <sub>AS</sub>	960	mJ
Repetitive Avalanche Current <sup>a</sup>		I <sub>AR</sub>	- 21	A
Repetitive Avalanche Energy <sup>a</sup>		E <sub>AR</sub>	18	mJ
Maximum Power Dissipation	T <sub>C</sub> = 25 °C	PD	180	W
Peak Diode Recovery dV/dt <sup>c</sup>	•	dV/dt	- 5.5	V/ns
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to + 175	°C
Soldering Recommendations (Peak Temperature) for 10 s			300 <sup>d</sup>	
Mounting Torque	6-32 or M3 screw		10	lbf ∙ in
Mounting Torque	0-32 of IVI3 Screw		1.1	N · m

#### Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11). b. V<sub>DD</sub> = - 25 V, starting T<sub>J</sub> = 25 °C, L = 3.3 mH, R<sub>g</sub> = 25  $\Omega$ , I<sub>AS</sub> = - 21 A (see fig. 12). c. I<sub>SD</sub>  $\leq$  - 21 A, dI/dt  $\leq$  200 A/µs, V<sub>DD</sub>  $\leq$  V<sub>DS</sub>, T<sub>J</sub>  $\leq$  175 °C.

d. 1.6 mm from case.

\* Pb containing terminations are not RoHS compliant, exemptions may apply

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THERMAL RESISTANCE RATI	NGS							
PARAMETER	SYMBOL	TYP.		MAX.			UNIT	
Maximum Junction-to-Ambient	R <sub>thJA</sub>	-		40				
Case-to-Sink, Flat, Greased Surface	R <sub>thCS</sub>	0.24 - - 0.83			°C/W			
Maximum Junction-to-Case (Drain)	R <sub>thJC</sub>							
<b>SPECIFICATIONS</b> ( $T_J = 25 \ ^{\circ}C$ , $T_J = 25 \ ^{\circ}C$ )	unless otherw	vise noted)						
PARAMETER	SYMBOL	TEST (	CONDIT	IONS	MIN.	TYP.	MAX.	UNIT
Static								
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0$ V	V, I <sub>D</sub> = - 2	250 µA	- 100	-	-	V
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{J}$	Reference to	o 25 °C, I	<sub>D</sub> = - 1 mA	-	- 0.087	-	V/°C
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{G}$	<sub>S</sub> , I <sub>D</sub> = -	250 µA	- 2.0	-	- 4.0	V
Gate-Source Leakage	I <sub>GSS</sub>	V <sub>GS</sub>	$s = \pm 20$	V	-	-	± 100	nA
		V <sub>DS</sub> = - 1	00 V, V <sub>G</sub>	<sub>S</sub> = 0 V	-	-	- 100	
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = - 80 V, V	<sub>GS</sub> = 0 V	, T <sub>J</sub> = 150 °C	-	-	- 500	μA
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 10 V	١ <sub>c</sub>	<sub>0</sub> = - 13 A <sup>b</sup>	-	-	0.20	Ω
Forward Transconductance	9 <sub>fs</sub>	V <sub>DS</sub> = - 5	0 V, I <sub>D</sub> =	- 13 A <sup>b</sup>	6.2	-	-	S
Dynamic		•						
Input Capacitance	C <sub>iss</sub>	$V_{GS} = 0 V,$ $V_{DS} = -25 V,$ f = 1.0 MHz, see fig. 5		-	1400	-		
Output Capacitance	C <sub>oss</sub>			-	590	-	pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			-	140	-		
Total Gate Charge	Qg				-	-	61	
Gate-Source Charge	Q <sub>gs</sub>	V <sub>GS</sub> = - 10 V		A, V <sub>DS</sub> = - 80 V, fig. 6 and 13 <sup>b</sup>	-	-	14	nC
Gate-Drain Charge	Q <sub>gd</sub>		000	ig. o and to	-	-	29	
Turn-On Delay Time	t <sub>d(on)</sub>				-	16	-	
Rise Time	t <sub>r</sub>	V <sub>DD</sub> = - 5	0 V Ia –	- 10 A	-	73	-	
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_{g} = 9.1 \Omega, R_{D}$			-	34	-	ns
Fall Time	t <sub>f</sub>				-	57	-	
Internal Drain Inductance	L <sub>D</sub>	Between lead, 6 mm (0.25") from			-	5.0	-	
Internal Source Inductance	L <sub>S</sub>	package and cer die contact	nter of		-	13	-	nH
Drain-Source Body Diode Characteristic	s							
Continuous Source-Drain Diode Current	I <sub>S</sub>	MOSFET symbol showing the		-	-	- 21	А	
Pulsed Diode Forward Current <sup>a</sup>	I <sub>SM</sub>	integral reverse p - n junction dic	ode		-	-	- 84	
Body Diode Voltage	$V_{SD}$	$T_J = 25 \ ^\circ C, I_S$	= - 21 A	, $V_{GS} = 0 V^{b}$	-	-	- 5.0	V
Body Diode Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C, I <sub>F</sub> = -	19 쇼 세	/dt – 100 ∆/ue <sup>b</sup>	-	130	260	ns
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	·J = 20 0, IF = -	10 /A, UI	αι – 100 Αγμος	-	0.35	0.70	μC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-	on time	is negligible (turn	I-on is doi	minated b	y L <sub>S</sub> and	L <sub>D</sub> )

#### Notes

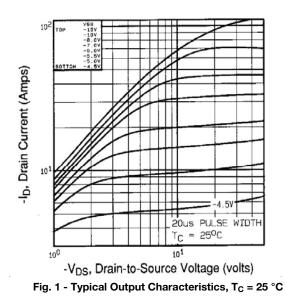
a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11).

b. Pulse width  $\leq$  300 µs; duty cycle  $\leq$  2 %.

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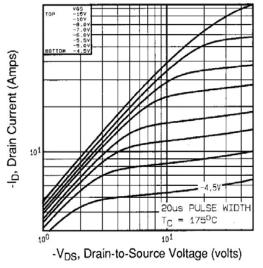


Fig. 2 - Typical Output Characteristics,  $T_C$  = 175 °C

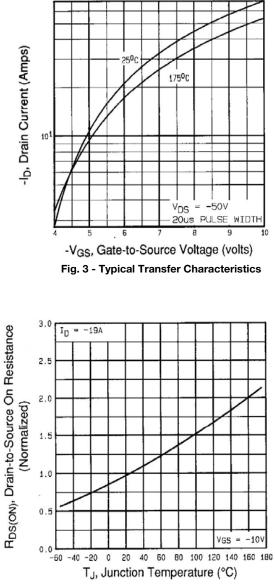


Fig. 4 - Normalized On-Resistance vs. Temperature

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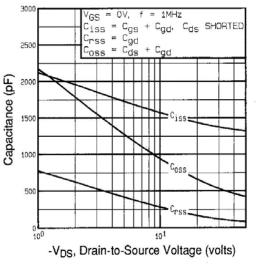
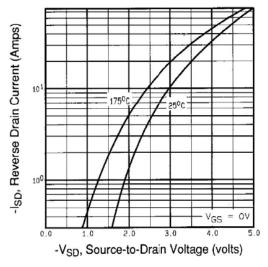


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage





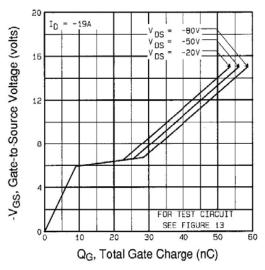


Fig. 6 - Typical Gate Charge vs. Gate-to-Source Voltage

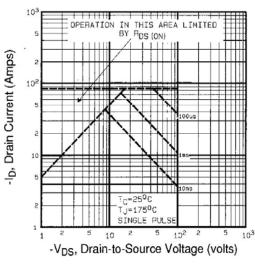


Fig. 8 - Maximum Safe Operating Area



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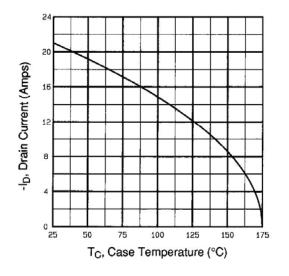


Fig. 9 - Maximum Drain Current vs. Case Temperature

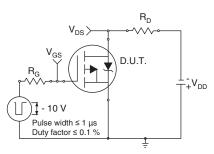


Fig. 10a - Switching Time Test Circuit

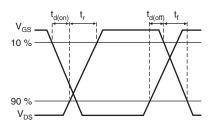


Fig. 10b - Switching Time Waveforms

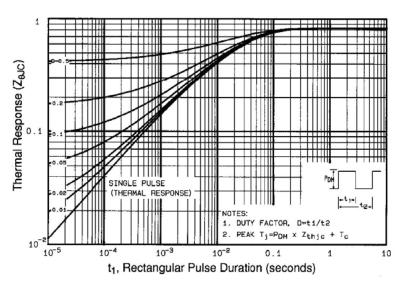


Fig. 11 - Maximum Effective Transient Thermal Impedance, Junction-to-Case

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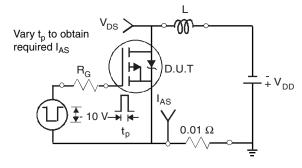


Fig. 12a - Unclamped Inductive Test Circuit

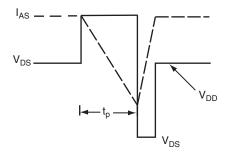


Fig. 12b - Unclamped Inductive Waveforms

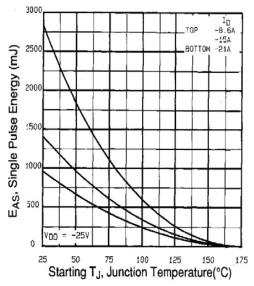
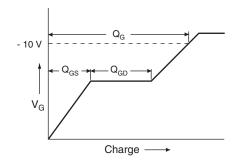
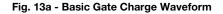


Fig. 12c - Maximum Avalanche Energy vs. Drain Current





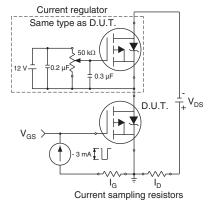


Fig. 13b - Gate Charge Test Circuit

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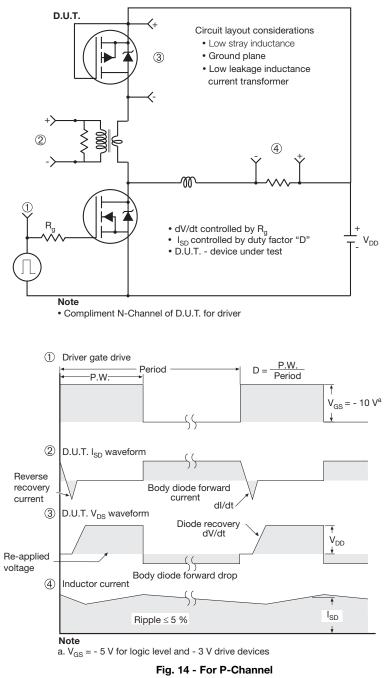
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# **TO-247AC (High Voltage)**

### VERSION 1: FACILITY CODE = 9





Section C--C, D--D, E--E

	MILLIN	IETERS	
DIM.	MIN.	MAX.	NOTES
А	4.83	5.21	
A1	2.29	2.55	
A2	1.50	2.49	
b	1.12	1.33	
b1	1.12	1.28	
b2	1.91	2.39	6
b3	1.91	2.34	
b4	2.87	3.22	6, 8
b5	2.87	3.18	
С	0.55	0.69	6
c1	0.55	0.65	
D	20.40	20.70	4

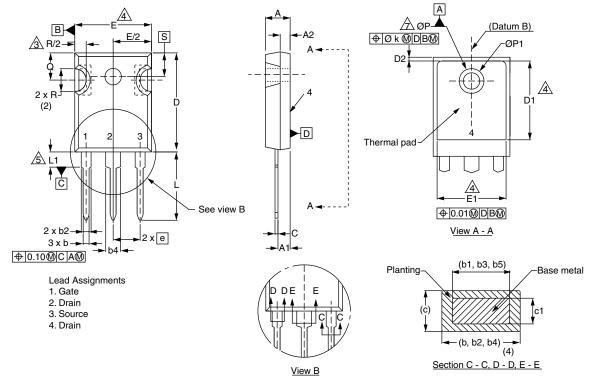
	MILLIN	IETERS	
DIM.	MIN.	MAX.	NOTES
D1	16.25	16.85	5
D2	0.56	0.76	
E	15.50	15.87	4
E1	13.46	14.16	5
E2	4.52	5.49	3
е	5.44	BSC	
L	14.90	15.40	
L1	3.96	4.16	6
ØР	3.56	3.65	7
Ø P1	7.19	) ref.	
Q	5.31	5.69	
S	5.54	5.74	

#### Notes

- <sup>(1)</sup> Package reference: JEDEC<sup>®</sup> TO247, variation AC
- (2) All dimensions are in mm
- <sup>(3)</sup> Slot required, notch may be rounded
- (4) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm per side. These dimensions are measured at the outermost extremes of the plastic body
- <sup>(5)</sup> Thermal pad contour optional with dimensions D1 and E1
- (6) Lead finish uncontrolled in L1
- (7) Ø P to have a maximum draft angle of 1.5° to the top of the part with a maximum hole diameter of 3.91 mm
- (8) Dimension b2 and b4 does not include dambar protrusion. Allowable dambar protrusion shall be 0.1 mm total in excess of b2 and b4 dimension at maximum material condition



### **VERSION 2: FACILITY CODE = Y**



	MILLIN	IETERS	
DIM.	MIN.	MAX.	NOTES
А	4.58	5.31	
A1	2.21	2.59	
A2	1.17	2.49	
b	0.99	1.40	
b1	0.99	1.35	
b2	1.53	2.39	
b3	1.65	2.37	
b4	2.42	3.43	
b5	2.59	3.38	
с	0.38	0.86	
c1	0.38	0.76	
D	19.71	20.82	
D1	13.08	-	

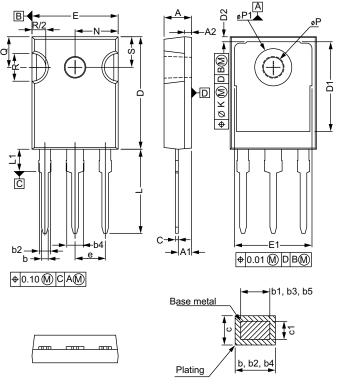
	MILLIN	IETERS	
DIM.	MIN.	MAX.	NOTES
D2	0.51	1.30	
E	15.29	15.87	
E1	13.72	-	
е	5.46	BSC	
Øk	0.2	254	
L	14.20	16.25	
L1	3.71	4.29	
ØΡ	3.51	3.66	
Ø P1	-	7.39	
Q	5.31	5.69	
R	4.52	5.49	
S	5.51	BSC	

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- <sup>(3)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- <sup>(5)</sup> Lead finish uncontrolled in L1
- <sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- <sup>(7)</sup> Outline conforms to JEDEC outline TO-247 with exception of dimension c



### VERSION 3: FACILITY CODE = N



	MILLIN	IETERS		MILLIN	<b>IETERS</b>
DIM.	MIN.	MAX.	DIM.	MIN.	MAX.
А	4.65	5.31	D2	0.51	1.35
A1	2.21	2.59	E	15.29	15.87
A2	1.17	1.37	E1	13.46	-
b	0.99	1.40	е	5.46	BSC
b1	0.99	1.35	k	0.:	254
b2	1.65	2.39	L	14.20	16.10
b3	1.65	2.34	L1	3.71	4.29
b4	2.59	3.43	N	7.62	BSC
b5	2.59	3.38	Р	3.56	3.66
С	0.38	0.89	P1	-	7.39
c1	0.38	0.84	Q	5.31	5.69
D	19.71	20.70	R	4.52	5.49
D1	13.08	-	S	5.51	BSC

Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(4)</sup> Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")



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